

L2*735/2*850-40B52-1

Multi-Wavelength LED

L2*735/2*850-40B52-1 consists of AIGaAs LEDs mounted with AIN heat sink pedestal on TO-18 5pins type stem with flat glass lens can. Each chips are connected as series.

<Specifications>

1. Product Name: Multi-Wavelength LED Lamp 2. Type Number: L2*735/2*850-40B52-1

3. Chip:

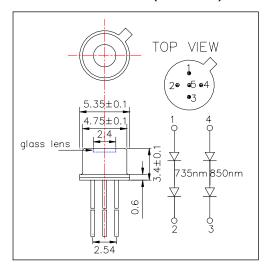
- Chip material: AlGaAs

- Peak Wavelength: 735nm and 850nm typ.

4.Package

Stem: TO-18 5pin typeLens: Φ2.4 flat glass

Outer Dimension (Unit:mm)



Absolute Maximum Ratings [Ta=25 $^{\circ}$ C]											
Item	Symbol	Maximum F	l lmih								
		735	850	Unit							
Power Dissipation	PD	180	160	mW							
Forward Current	IF	75	100	mA							
Pulse Forward Current	IF	200	500	mA							
Reverse Voltage	VR	ī	V								
Operating Temperature	TOPR	-20 ^	$^{\circ}$								
Storage Temperature	TSTG	-30 ~	$^{\circ}$								
Soldering Temperature*	TSOL	24	$^{\circ}$								

^{*} Soldering condition must be completed within 3 seconds at 240 and is allowed in the area apart 3mm from the bottom of the lamp.

Floatro Ontical Characteristics [Ta=25°C]										
Electro-Optical Characteristics [Ta=25°C]										
Item	Symbol	Condition	Minimum		Typical		Maximum		Unit	
			735	850	735	850	735	850	Offic	
Forward Voltage	VF	IF=50mA			3.70	3.00	4.60	3.40	V	
Reverse Current	IR	VR=5V					10		uA	
Total Radiated Power*	РО	IF=50mA	8.0	8.0	14.0	14.0			mW	
Peak Wavelength	λР	IF=50mA	710	835	735	850	755	865	nm	
Half Width	Δλ	IF=50mA			40	40			nm	

^{*}Measured by Photodyne #500.

